

PF0464.153NL Datasheet

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DiGi Electronics Part Number	PF0464.153NL-DG
Manufacturer	Pulse Electronics
anufacturer Product Number	PF0464.153NL
Description	FIXED IND 15UH 2.35A 75 MOHM SMD
Detailed Description	15 μH Shielded Inductor 2.35 A 75mOhm Max Nons tandard

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Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PF0464.153NL	Pulse Electronics
Series:	Product Status:
PF0464NL	Active
Туре:	Material - Core:
Inductance:	Tolerance:
15 μΗ	±20%
Current Rating (Amps):	Current - Saturation (Isat):
2.35 A	1.4A
Shielding:	DC Resistance (DCR):
Shielded	75mOhm Max
Q @ Freq:	Frequency - Self Resonant:
	24MHz
Ratings:	Operating Temperature:
	-40°C ~ 125°C
Inductance Frequency - Test:	Features:
100 kHz	
Mounting Type:	Package / Case:
Surface Mount	Nonstandard
Supplier Device Package:	Size / Dimension:
	0.283" L x 0.283" W (7.20mm x 7.20mm)
Height - Seated (Max):	
0.118" (3.00mm)	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8504.50.4000	

SMT Power Inductors

Shielded Drum Core - PF0464NL/PF0465NL Series





- *•* **Height:** PF0464: 3mm Max PF0465: 4mm Max
- *•* **Footprint:** 7.2mm x 7.2mm Max
- *Current Rating:* PF0464: up to 4.5A PF0465: up to 3.5A
- *P* Inductance Range: 1.5μH to 100μH

	Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C ^{1,6}								
	Inductance Inductance DCR (mΩ) Saturation ⁶ Heating ⁷ Core Loss ⁸								
Part ^{2,3} Number	@ 0ADC (µH ±20%)	@ Irated (µH TYP)	Irated⁵ (A)	ТҮР	MAX	Current I sat -20% (A)	Current IDC +40°C (A)	Factor (K2)	SFR (MHz)
PF0464NL Series									
PF0464.152NL	1.5	1.2	4.50	9	12	4.50	5.50	660	>40
PF0464.302NL	3.0	2.4	3.00	17	22	3.00	4.25	850	>40
PF0464.392NL *	3.9	3.1	2.60	19	25	2.60	3.80	990	>40
PF0464.502NL	5.0	4.0	2.40	24	30	2.40	3.55	1100	>40
PF0464.602NL	6.0	4.8	2.25	26	33	2.25	3.20	1300	>40
PF0464.732NL	7.3	5.8	2.10	36	45	2.10	3.10	1400	>40
PF0464.862NL *	8.6	6.9	1.85	38	48	1.85	2.95	1500	35
PF0464.103NL	10	8.0	1.70	41	52	1.70	2.90	1700	32
PF0464.123NL *	12	9.6	1.55	52	66	1.55	2.40	1800	26
PF0464.153NL	15	12.0	1.40	55	75	1.40	2.35	2000	24
PF0464.183NL	18	14.4	1.32	69	90	1.32	2.10	2200	22
PF0464.223NL	22	17.6	1.20	85	113	1.20	1.85	2500	21
PF0464.273NL *	27	21.6	1.05	104	132	1.05	1.70	2800	19
PF0464.333NL *	33	26.4	0.97	132	165	0.97	1.50	3000	18
PF0464.393NL *	39	31.2	0.86	142	180	0.86	1.45	3300	14
PF0464.473NL *	47	37.6	0.80	197	238	0.80	1.25	3600	14
PF0464.563NL *	56	44.8	0.73	216	270	0.73	1.15	3900	13
PF0464.683NL	68	54.4	0.65	235	300	0.65	1.10	4400	12
PF0464.823NL *	82	65.6	0.60	291	370	0.60	1.00	4800	11
PF0464.104NL *	100	80.0	0.54	401	505	0.54	0.85	5300	10.5

Notes:

1. Inductance is measure, where applicable, with both primary windings connected in series (2 to 5, with 3 and 4 shorted).

2. Leakage inductance is measured with both primary windings connected in series (where applicable) with all other windings shorted.

*Contact Pulse for availability

SMT Power Inductors Shielded Drum Core - PF0464NL/PF0465NL Series

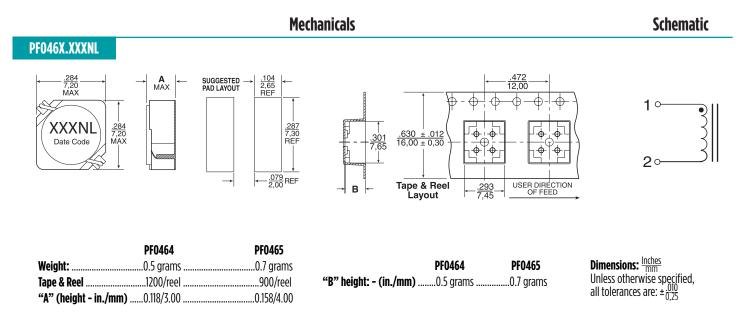


Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C ^{1,6}									
Part ^{2,3}	Inductance @OADC	Inductance @ Irated	Irated ⁵	DCR	(mΩ)	Saturation ⁶ Current Isat	Heating ⁷ Current IDC	Core Loss ⁸ Factor	SFR
Number	(µH ±20%)	(µHTYP)	(A)	TYP	MAX	-20% (A)	+40°C (A)	(K2)	(MHz)
PF0465NL Series									
PF0465.332NL	3.3	2.6	3.50	16	20	3.50	4.65	790	>40
PF0465.502NL	5.0	4.0	2.90	19	24	2.90	4.10	970	>40
PF0465.622NL	6.2	5.0	2.50	21	26	2.50	3.90	1100	>40
PF0465.732NL	7.3	5.8	2.30	25	31	2.30	3.50	1200	>40
PF0465.862NL *	8.6	6.9	2.20	27	34	2.20	3.30	1300	35
PF0465.103NL	10	8.0	2.00	29	37	2.00	3.20	1400	32
PF0465.123NL	12	9.6	1.70	39	50	1.70	2.80	1600	26
PF0465.153NL	15	12.0	1.60	44	55	1.60	2.60	1700	24
PF0465.183NL *	18	14.4	1.50	62	78	1.50	2.25	1900	22
PF0465.223NL	22	17.6	1.30	68	86	1.30	2.10	2100	21
PF0465.273NL	27	21.6	1.20	75	95	1.20	2.00	2300	19
PF0465.333NL *	33	26.4	1.10	94	118	1.10	1.75	2500	18
PF0465.393NL	39	31.2	1.00	101	128	1.00	1.70	2800	17
PF0465.473NL	47	37.6	0.95	112	140	0.95	1.60	3000	14
PF0465.563NL *	56	44.8	0.85	154	195	0.85	1.35	3300	13
PF0465.683NL	68	54.4	0.75	188	234	0.75	1.25	3700	12
PF0465.823NL *	82	65.6	0.70	261	324	0.70	1.05	4000	11
PF0465.104NL	100	80.0	0.65	286	350	0.65	1.00	4500	10.5

SMT Power Inductors

Shielded Drum Core - PF0464NL/PF0465NL Series





Notes:

- 1. Unless otherwise specified, all testing is made at 100kHz, 0.1VAC.
- Optional Tape & Reel packaging can be ordered by adding a "T" suffix to the part number (i.e P1166.102NL becomes P1166.102NLT). Pulse complies with industry standard Tape and Tape & Reel specification EIA481.
- 3. The "NL" suffix indicates an RoHS-compliant part numer. Non-NL suffixed parts are not necessarily RoHS compliant, but are electrically and mechanically equivalent to NL versions. If a part number does not have the "NL" version, but an RoHS compliant version is required, please contact Pulse for availability.
- 4. Temperature of the component (ambient plus temperature rise) must be within specified operating temperature range.
- 5. The rated current (lrated) as listed is either the saturation current or the heating current depending on which value is lower.
- 6. The saturation current, lsat, is the current at which the component inductance drops by the indicated percentage (typical) at an ambient temperature of 25C. This current is determined by placing the component in the specified ambient environment and applying a short duration pulse current (to eliminate self-heating effects) to the component.
- 7. The heating current, Idc, is the DC current required to raise the component temperature by the indicated delta (approximately). The heating current isdetermined by mounting the component on a typical PCB and applying current for 30 minutes. The temperature is measured by placing the thermocouple on top of the unit under test.

8. In high volt*time (Et) or ripple current applications, additional heating in the component can occur due to core losses in the inductor which may necessitate derating the current in order to limit the temperature rise of the component. In order to determine the approximate total loss (or temperature rise) for a given application, both copper losses and core losses should be taken into account.

Estimated Temperature Rise:

Trise = [Total loss (mW) / K0]⁸³³(°C) Total Loss = Copper loss + Core loss (mW) Copper loss = $I_{RMS}^2 \times DCR$ (Typical) (mW) Irms = $[I_{DC}^2 + \Delta I^2 / 12]^{V/2}$ (A) Core loss = K1 x f (kHz)^{1.23} x Bac (Ga)^{2.38} (mW) Bac (peak to peak flux density) = K2 x ΔI (Ga) [= K2/L (µH) x Et (V-µSec) (Ga)]

where f varies between 25kHz and 1MHz, and Bac is less than 2500 Gauss.

K2 is a core size and winding dependent value and is given for each p/n in the proceeding datasheets. K0 & K1 are platform and material dependant constants and are given in the table below for each platform.

SMT Power Inductors Shielded Drum Core - PF0464NL/PF0465NL Series

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Part N	Io. (KO)	Core Loss Factor (K1)		
PG0085	5/86 2.3	5.29E-10	_	
PG00	87 5.8	15.2E-10		
PG004	0/41 0.8	2.80E-10	CoreLoss/K1 Vs Flux Density	
P117	4 0.8	6.47E-10	3.00E+10 2.50E+10	- 100KHz
PF06	01 4.6	14.0E-10		— 200КНz
PF04	64 3.6	24.7E-10	2.00E+10	- 300KHz
PF04	65 3.6	33.4E-10	_ S 1.50E+10	- 400KHz
P116	6 1.9	29.6E-10		← 500KHz
P116	7 2.1	42.2E-10		— 700KHz
PF0560	DNL 5.5	136E-10	o	— 1.0MHz
P1168/	/69 4.8	184E-10	0 500 1000 1500 2000 2500	
P1170,	/71 4.3	201E-10	Δ B (Gauss) where ΔB = K2 x ΔI [= K2/L(μH) x Et(V-μSec)]	
P1172/	/73 5.6	411E-10		
PF0552	2NL 8.3	201E-10	-	
PF0553	SNL 7.1	411E-10	-	

Take note that the component's temperature rise varies depending on the system condition. It is suggested that the component be tested at the system level, to verify the temperature rise of the component during system operation.

For More Information Pulse Worldwide Headquarters 15255 Innovation Drive Ste 100 San Diego, CA 92128 U.S.A.	Pulse Europe Pulse Electronics GmbH Am Rottland 12 58540 Meinerzhagen Germany	Pulse China Headquarters Pulse Electronics (ShenZhen) CO., LTD D708, Shenzhen Academy of Aerospace Technology, The 10th Keji South Road, Nanshan District, Shenzhen, P.R. China 518057	Pulse North China Room 2704/2705 Super Ocean Finance Ctr. 2067 Yan An Road West Shanghai 200336 China	Pulse South Asia 3 Fraser Street 0428 DUO Tower Singapore 189352	Pulse North Asia 1F., No.111 Xiyuan Road Zhongli District Taoyuan City 32057 Taiwan (R.O.C)
Tel: 858 674 8100	Tel: 49 2354 777 100	Tel: 86 755 33966678	Tel: 86 21 62787060	Tel: 65 6287 8998	Tel: 886 3 4356768
Fax: 858 674 8262	Fax: 49 2354 777 168	Fax: 86 755 33966700	Fax: 86 2162786973	Fax: 65 6280 0080	Fax: 886 3 4356820

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